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# Epitaxial growth and magnetic properties of thin transition metal films on hydrogen passivated silicon surfaces

## Fact Sheet

### Project Information

Grant agreement ID: FMBI950399

Project closed

**Start date**

1 March 1996

**End date**

28 February 1997

**Funded under**

Specific research and technological development programme in the field of the training and mobility of researchers, 1994-1998


**Total cost**

No data

**EU contribution**

No data

**Coordinated by**

CENTRE NATIONAL DE LA  
RECHERCHE SCIENTIFIQUE  
 France

## Objective

One of the main objectives of the present proposal is the realization of epitaxial growth of thin metallic films particularly of ferromagnetic materials as Co and Fe on

Si(111)1x1-H and Si(113)1x1-H surfaces. These systems will be prepared wet chemically and electrochemically following well established recipes. Under certain growth conditions the deposition on these substrates is believed to form ideal Schottky- barriers if the H bond to the Si substrate surface can be conserved. The hydrogen passivation of the Si surface seems to remain upon metal deposition preventing the undesired silicide formation at the metal- semiconductor interface. One of my tasks will be to elucidate the optimum growth procedures by determining the critical factors during the process like substrate surface temperatures and metal deposition rates. These experiments are of fundamental importance to provide appropriate multilayer systems for further investigations. Surface analysis techniques like LEED, IRAS, ARUPS and synchrotron radiation will be used to characterize the growth mechanism and the dynamic and magnetic properties of the metal- semiconductor systems.

## Fields of science (EuroSciVoc)

[natural sciences](#) > [physical sciences](#) > [electromagnetism and electronics](#) > **[semiconductivity](#)**

[natural sciences](#) > [chemical sciences](#) > [inorganic chemistry](#) > **[metalloids](#)**



## Programme(s)

[FP4-TMR - Specific research and technological development programme in the field of the training and mobility of researchers, 1994-1998](#)

## Topic(s)

[0302 - Post-doctoral research training.grants](#)

[TP13 - Surface Physics](#)

## Call for proposal

Data not available

## Funding Scheme

[RGI - Research grants \(individual fellowships\).](#)

# Coordinator



## CENTRE NATIONAL DE LA RECHERCHE SCIENTIFIQUE

EU contribution

No data

Total cost

No data

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## Participants (1)



Not available

 Germany

EU contribution

No data

Address



Total cost

No data

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